

NHD-C0216AZ-FN-GBW

COG (Chip-on-Glass) Liquid Crystal Display Module

NHD-	Newhaven Display
C0216-	COG, 2 Lines x 16 Characters
AZ-	Model
F-	Transflective
N-	No Backlight
G-	STN Positive Gray
B-	6:00 Optimal View
W-	Wide Temp
	RoHS Compliant

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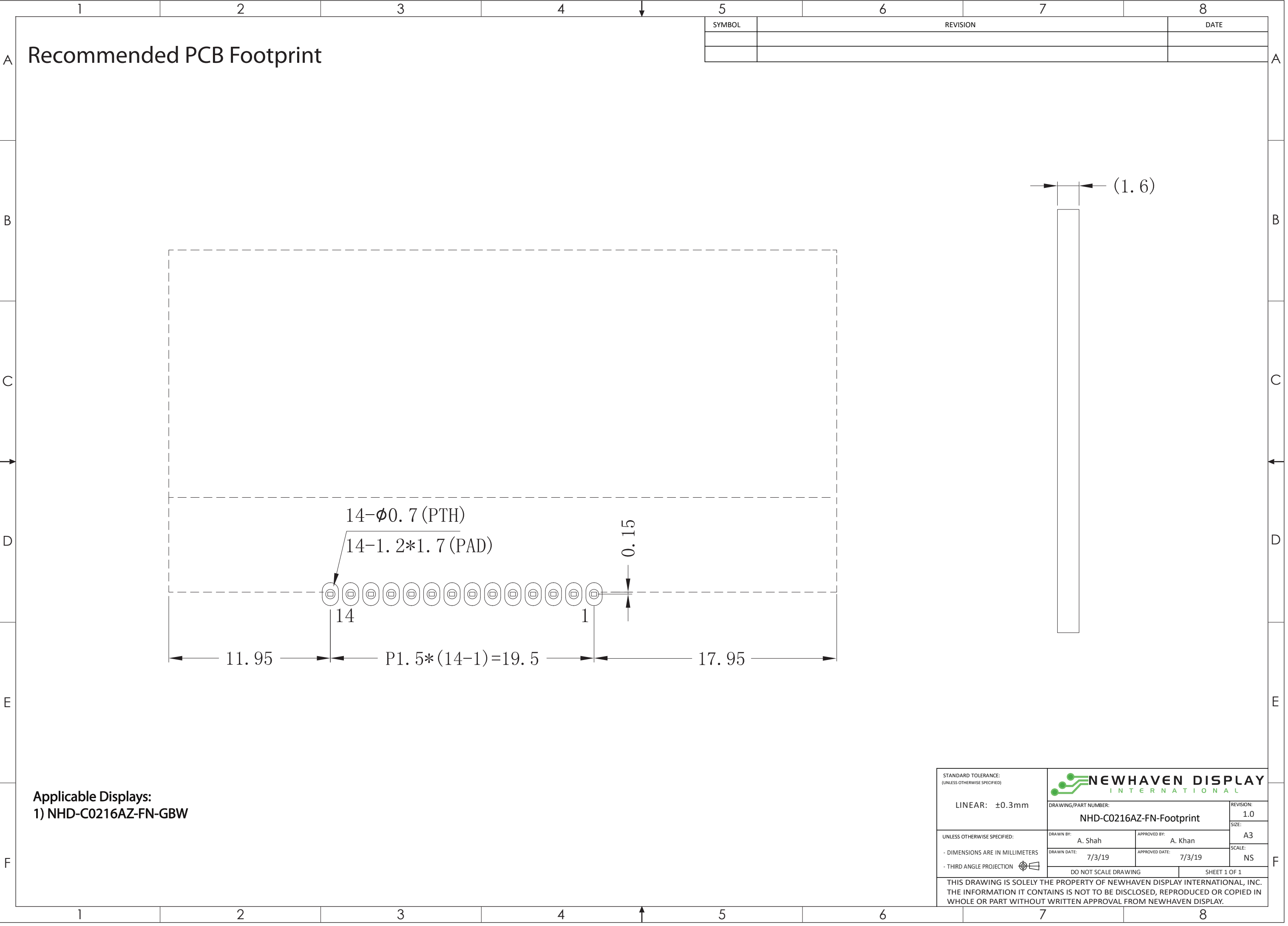
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Document Revision History

Revision	Date	Description	Changed by
0	7/20/07	Initial Release	-
1	8/1/07	Edit temp. range errors	CL
2	6/4/08	Edit incorrect pinout	CL
3	9/9/09	User guide reformat	BE
4	10/9/09	Updated Electrical Characteristics information	MC
5	10/15/09	Updated Block Diagram	MC
6	6/2/11	Timing characteristics updated	AK
7	4/14/17	Updated Mechanical Drawing	TM
8	7/5/19	Added PCB Footprint Drawing	AS
9	1/30/20	Glass Panel Updated	SB

Functions and Features

- 2 lines x 16 characters
- Built-in NT7605 controller
- 5x8 dots with cursor
- +5V power supply
- 1/16 duty, 1/5 bias
- RoHS Compliant

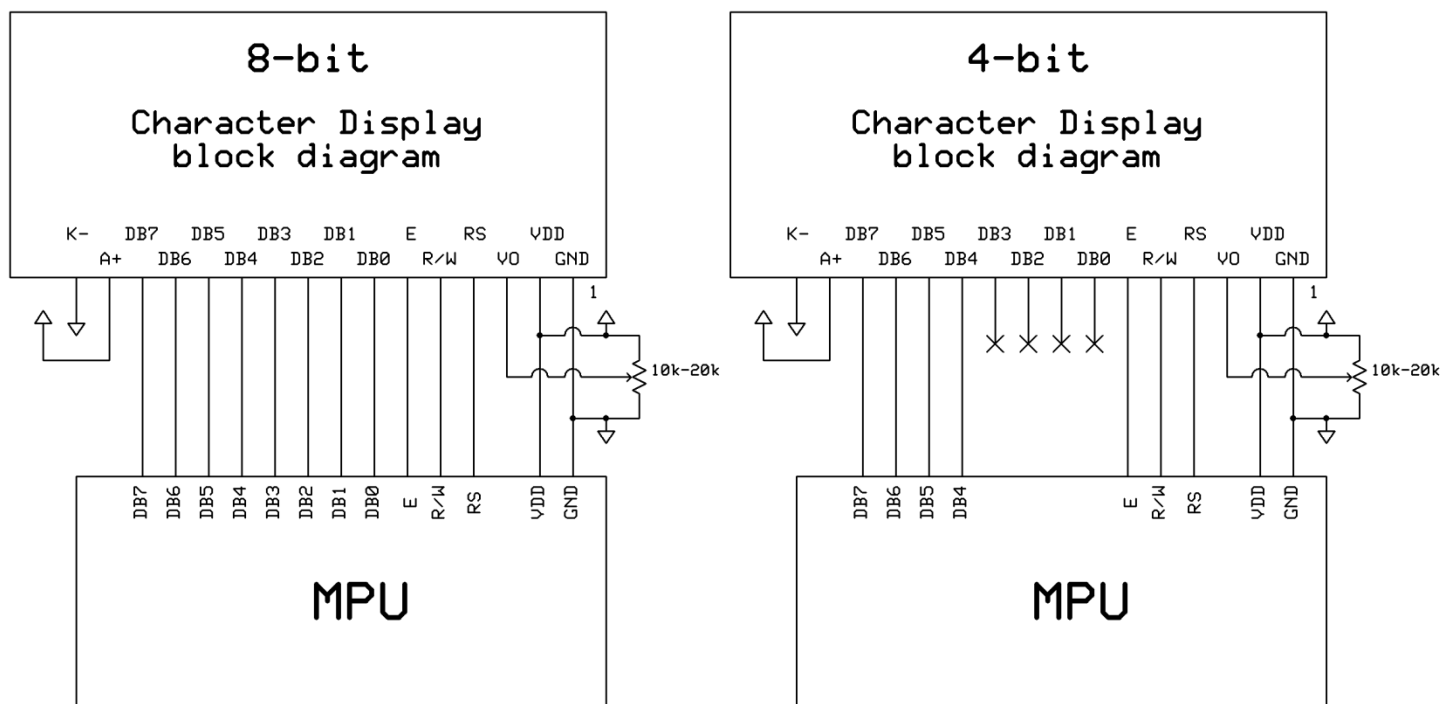


Pin Description and Wiring Diagram

Pin No.	Symbol	External Connection	Function Description
1	V _{SS}	Power Supply	Ground
2	V ₀	Adj. Power supply	Power supply for contrast (approx. 0.3V)
3	V _{DD}	Power Supply	Supply voltage for logic (5.0V)
4	RS	MPU	Register select signal. RS=0: Command, RS=1: Data
5	R/W	MPU	Read/Write select signal, R/W=1: Read R/W=0: Write
6	E	MPU	Operation enable signal. Falling edge triggered.
7-10	DB0-DB3		Four low order bi-directional three state data bus lines. These four are not used during 4-bit operation.
11-14	DB4-DB7		Four high order bi-directional three state data bus lines.

Recommended LCD connector: 1.5 mm pitch, 14 pins Soldered to PCB

Recommended Breakout Board: [NHD-PCB40](#)



Electrical Characteristics

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Operating Temperature Range	T _{OP}	Absolute Max	-20	-	+70	°C
Storage Temperature Range	T _{ST}	Absolute Max	-30	-	+80	°C
Supply Voltage	V _{DD}	-	4.5	5.0	5.5	V
Supply Current	I _{DD}	T _{OP} = 25°C, V _{DD} = 5.0V	0.6	1.83	2.8	mA
Supply for LCD (contrast)	V _{LCD}		4.4	4.7	5.0	V
"H" Level input	V _{IH}	-	0.8 * V _{DD}	-	V _{DD}	V
"L" Level input	V _{IL}	-	V _{SS}	-	0.2 * V _{DD}	V
"H" Level output	V _{OH}	-	V _{DD} - 0.8	-	V _{DD}	V
"L" Level output	V _{OL}	-	V _{SS}	-	V _{SS} + 0.4	V

Optical Characteristics

Item		Symbol	Condition	Min.	Typ.	Max.	Unit
Optimal Viewing Angles	Top	φY+	CR ≥ 2	-	35	-	°
	Bottom	φY-		-	60	-	°
	Left	θX-		-	40	-	°
	Right	θX+		-	40	-	°
Contrast Ratio		CR	-	2	4	-	-
Response Time	Rise	T _R	T _{OP} = 25°C	-	150	250	ms
	Fall	T _F		-	150	250	ms

Controller Information

Built-in NT7605 Controller.

Please download specification at http://www.newhavendisplay.com/app_notes/NT7605.pdf

DDRAM address location:

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
00	01	02	03	04	05	06	07	08	09	0A	0B	0C	0D	0E	0F
40	41	42	43	44	45	46	47	48	49	4A	4B	4C	4D	4E	4F

Table of Commands

Instruction	Code										Function	Execution time (max) (fosc = 250KHz)	
	RS	RW	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0			
Display Clear	0	0	0	0	0	0	0	0	0	1	Clear entire display area, Restore display from shift, and load address counter with DD RAM address 00H.	1.64ms	
Display/ Cursor Home	0	0	0	0	0	0	0	0	0	1	*	Restore display from shift and load address counter with DD RAM address 00H.	1.64ms
Entry Mode Set	0	0	0	0	0	0	0	0	1	I/D	S	Specify direction of cursor movement and display shift mode. This operation takes place after each data transfer (read/write).	40μs
Display ON/OFF	0	0	0	0	0	0	0	1	D	C	B	Specify activation of display (D) cursor (C) and blinking of character at cursor position (B).	40μs
Display/ Cursor Shift	0	0	0	0	0	0	1	S/C	R/L	*	*	Shift display or move cursor.	40μs
Function Set	0	0	0	0	1	DL	N	F	*	*	*	Set interface data length (DL), number of display line (N), and character font (F).	40μs
RAM Address Set	0	0	0	1	ACG						Load the address counter with a CG RAM address. Subsequent data access is for CG RAM data.	40μs	
DD RAM Address Set	0	0	1	ADD						Load the address counter with a DD RAM address. Subsequent data access is for DD RAM data.	40μs		
Busy Flag/ Address Counter Read	0	1	BF	AC						Read Busy Flag (BF) and contents of Address Counter (AC).	1μs		
CG RAM/ DD RAM Data Write	1	0	Write data						Write data to CG RAM or DD RAM.			40μs	
CG RAM/ DD RAM Data Read	1	1	Read data						Read data from CG RAM or DD RAM.			40μs	
	I/D = 1 : Increment S = 1 : Display Shift On D = 1 : Display On C = 1 : Cursor Display On B = 1 : Cursor Blink On S/C = 1 : Shift Display R/L = 1 : Shift Right DL = 1 : 8-Bit N = 1 : Dual Line F = 1 : 5x10 dots BF = 1 : Internal Operation BF = 0 : Ready for Instruction											I/D = 0 : Decrement S/C = 0 : Move Cursor R/L = 0 : Shift Left DL = 0 : 4-Bit N = 0 : Signal Line F = 0 : 5x8 dots	DD RAM : Display Data RAM CG RAM : Character Generator RAM ACG : Character Generator RAM Address ADD : Display Data RAM Address AC : Address Counter

Timing Characteristics

Read Operation

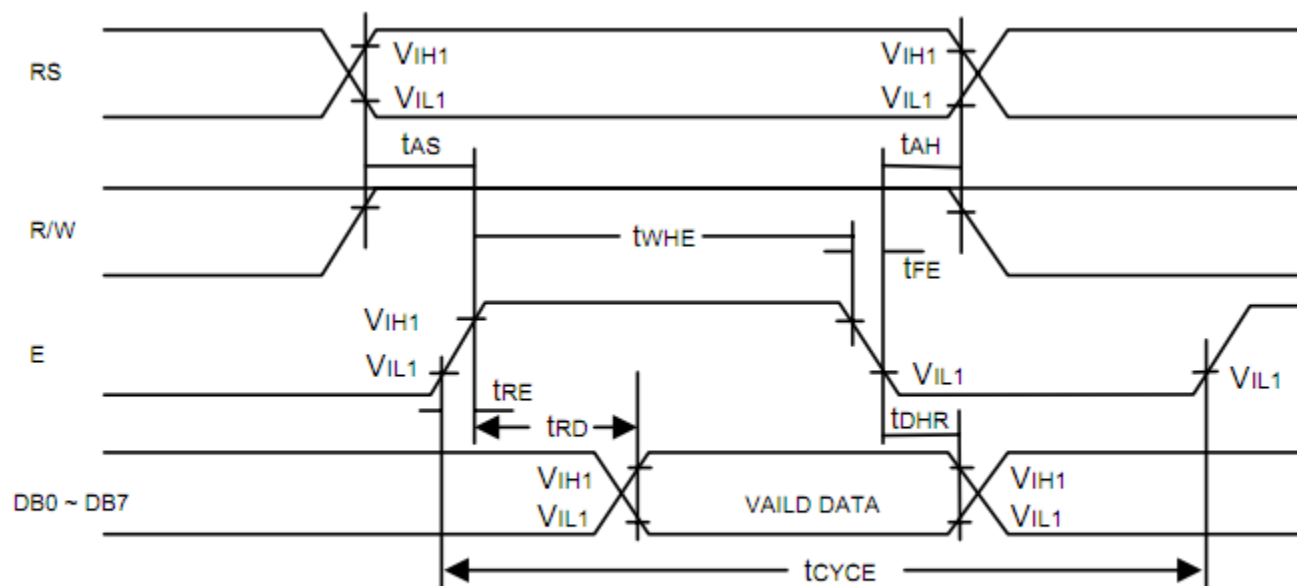


Figure 1. Bus Read Operation Sequence
(Reading out data from NT7605 to MPU)

Read Cycle ($V_{DD} = 5.0V$, $GND = 0V$, $T_A = 25^{\circ}C$)

Symbol	Parameter	Min.	Typ.	Max.	Unit	Conditions
tCYCE	Enable Cycle Time	500	-	-	ns	Figure 1
twHE	Enable "H" Level Pulse Width	300	-	-	ns	Figure 1
tRE, tFE	Enable Rise/Fall Time	-	-	25	ns	Figure 1
tAS	RS, R/W Setup Time	60 ¹	-	-	ns	Figure 1
		100 ²				
tAH	RS, R/W Address Hold Time	10	-	-	ns	Figure 1
tRD	Read Data Output Delay	-	-	190	ns	Figure 1
tDHR	Read Data Hold Time	20	-	-	ns	Figure 1

Notes: 1: 8-bit operation mode
2: 4-bit operation mode

Write Operation

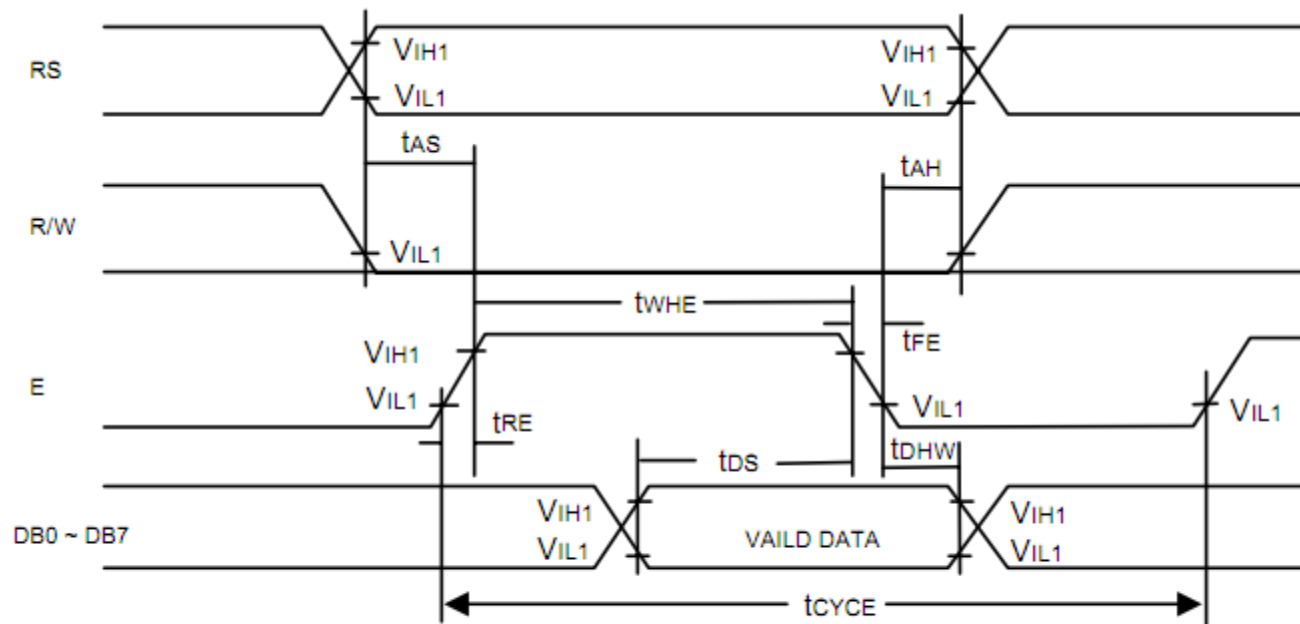


Figure 2. Bus Write Operation Sequence
(Writing data from MPU to NT7605)

Write Cycle ($V_{DD} = 5.0V$, $GND = 0V$, $T_A = 25^{\circ}C$)

Symbol	Parameter	Min.	Typ.	Max.	Unit	Conditions
tCYCE	Enable Cycle Time	500	-	-	ns	Figure 2
tWHE	Enable "H" Level Pulse Width	300	-	-	ns	Figure 2
tRE, tFE	Enable Rise/Fall Time	-	-	25	ns	Figure 2
tAS	RS, R/W Setup Time	60 ¹ 100 ²	-	-	ns	Figure 2
tAH	RS, R/W Address Hold Time	10	-	-	ns	Figure 2
tDS	Data Output Delay	100	-	-	ns	Figure 2
tDHW	Data Hold Time	10	-	-	ns	Figure 2

Notes: 1: 8-bit operation mode
2: 4-bit operation mode

Built-in Font Table

Lower 4 Bits \ Upper 4 Bits	0000	0001	0010	0011	0100	0101	0110	0111	1000	1001	1010	1011	1100	1101	1110	1111
xxxx0000	CG RAM (1)			0	a	P	`	P				-	タ	ミ	α	p
xxxx0001	(2)		!	1	A	Q	a	q			。	ア	チ	△	ä	q
xxxx0010	(3)		"	2	B	R	b	r			「	イ	ツ	×	ß	θ
xxxx0011	(4)		#	3	C	S	c	s			」	ウ	テ	モ	ε	∞
xxxx0100	(5)		\$	4	D	T	d	t			、	エ	ト	ト	μ	Ω
xxxx0101	(6)		%	5	E	U	e	u			・	オ	ナ	1	℃	ü
xxxx0110	(7)		&	6	F	V	f	v			ヲ	カ	ニ	ヨ	ρ	Σ
xxxx0111	(8)		'	7	G	W	g	w			フ	キ	ヌ	ラ	g	π
xxxx1000	(1)		(	8	H	X	h	x			ィ	ク	ネ	リ	フ	Σ
xxxx1001	(2)		)	9	I	Y	i	y			ウ	ケ	ル	ル	´	y
xxxx1010	(3)		*	:	J	Z	j	z			エ	コ	ハ	レ	j	≠
xxxx1011	(4)		+	;	K	[	k	{			オ	サ	ヒ	ロ	×	π
xxxx1100	(5)		,	<	L	¥	l				カ	シ	フ	ワ	Φ	π
xxxx1101	(6)		-	=	M	]	m	}			ユ	ズ	ハ	ン	も	÷
xxxx1110	(7)		。	>	N	^	n	→			ヨ	セ	ホ	°	ñ	
xxxx1111	(8)		/	?	O	_	o	+			ッ	リ	マ	°	ö	■

Example Initialization Program

```
'INIT-----
A = &H30
Call Writecom                                     'wake up
Waitms 100
Call Writecom                                     'wake up
Waitms 10
Call Writecom                                     'wake up
Waitms 10
A = &H38
'function set
Call Writecom
A = &H10
'shift display=no
Call Writecom
A = &H0C
'display on
Call Writecom
A = &H06
'entry mode set
Call Writecom
'-----
Sub Writecom
P1 = A
Reset P3.0
'instruction
Reset P3.7
'RW
Waitms 1
Set P3.4
'E
Waitms 1
Reset P3.4                                     'E
End Sub
'-----
Sub Writedata
P1 = A
Set P3.0
'data
Reset P3.7
'RW
Waitms 1
Set P3.4
'E
Waitms 1
Reset P3.4                                     'E
End Sub
'-----
```

Quality Information

Test Item	Content of Test	Test Condition		Note
High Temperature storage	Endurance test applying the high storage temperature for a long time.	+80°C, 96 Hrs.		2
Low Temperature storage	Endurance test applying the low storage temperature for a long time.	-30°C, 96 Hrs.		1,2
High Temperature Operation	Endurance test applying the electric stress (voltage & current) and the high thermal stress for a long time.	+70°C, 96 Hrs.		2
Low Temperature Operation	Endurance test applying the electric stress (voltage & current) and the low thermal stress for a long time.	-20°C, 96 Hrs.		1,2
High Temperature / Humidity Operation	Endurance test applying the electric stress (voltage & current) and the high thermal with high humidity stress for a long time.	+50°C, 90% RH, 96 Hrs.		1,2
Thermal Shock resistance	Endurance test applying the electric stress (voltage & current) during a cycle of low and high thermal stress.	0°C, 30min -> 25°C, 5min -> 50°C, 30min = 1 cycle For 10 cycles		
Vibration test	Endurance test applying vibration to simulate transportation and use.	10-55Hz, 1.5mm amplitude. 60 sec in each of 3 directions X, Y, Z For 15 minutes		3
Static electricity test	Endurance test applying electric static discharge. (5 Times)	Air: ±8KV	C: 150pF	
		Contact: ±4KV	R: 330Ω	

Note 1: No condensation to be observed.

Note 2: Conducted after 4 hours of storage at 25°C, 0%RH.

Note 3: Test performed on product itself, not inside a container.

Precautions for using LCDs/LCMs

See Precautions at www.newhavendisplay.com/specs/precautions.pdf

Warranty Information and Terms & Conditions

http://www.newhavendisplay.com/index.php?main_page=terms

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